

SANYO

No.2392A

2SK772

N-Channel Junction Silicon FET

AF Amp Applications

Applications

Variable resistors, analog switches, AF amp, constant-current circuit

Features

Adoption of FBET process

Absolute Maximum Ratings at Ta=25°C

			unit
Drain to Source Voltage	V_{DSX}	40	V
Gate to Source Voltage	V_{GDS}	-40	V
Gate Current	I_G	10	mA
Drain Current	I_D	20	mA
Allowable Power Dissipation	P_D	300	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

Electrical Characteristics at Ta=25°C

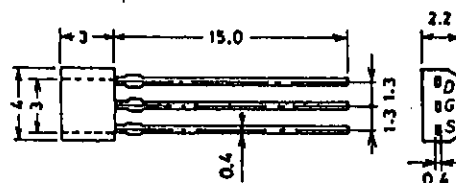
			min	typ	max	unit
Gate to Drain Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10\mu A, V_{DS} = 0$	-40			V
Gate Cutoff Current	I_{GSS}	$V_{GS} = -20V, V_{DS} = 0$			-1.0	nA
Cutoff Voltage	$I_{GS(off)}$	$V_{DS} = 10V, I_D = 1\mu A$	-0.3	-0.9	-2.5	V
Drain Current	I_{DSS}	$V_{DS} = 10V, V_{GS} = 0$	1.2*		12.0*	mA
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 10V, V_{GS} = 0, f = 1kHz$	4.5	9.0		mS
Input Capacitance	C_{iss}	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		9.0		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		2.1		pF
Noise Figure	NF	$V_{DS} = 10V, R_g = 1k\Omega, I_D = 1mA, f = 1kHz$		1.5		dB

*: The 2SK772 is classified by I_{DSS} as follows: (unit: mA)

1.2	D	3.0	2.5	E	6.0	5.0	F	12.0
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Package Dimensions 2034

(unit: mm)

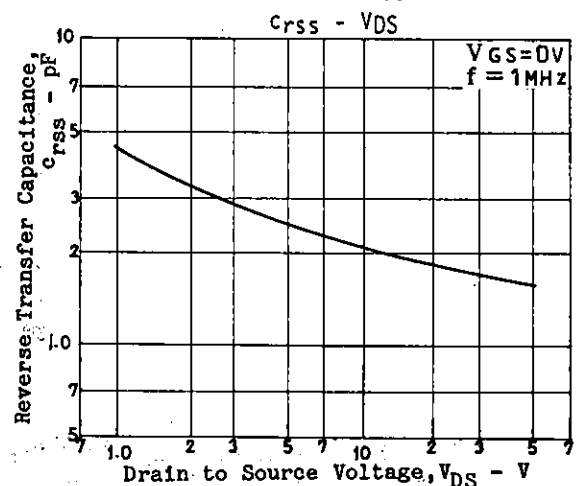
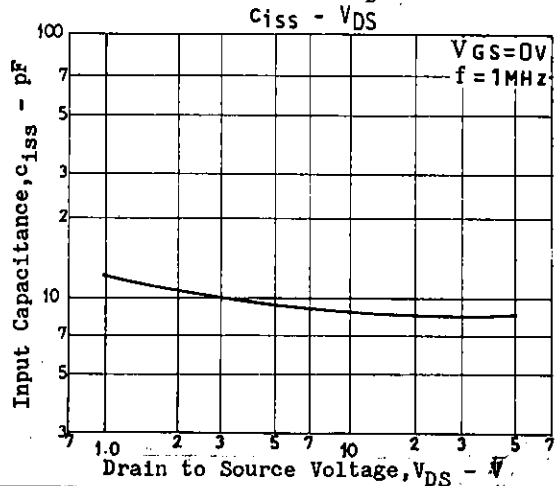
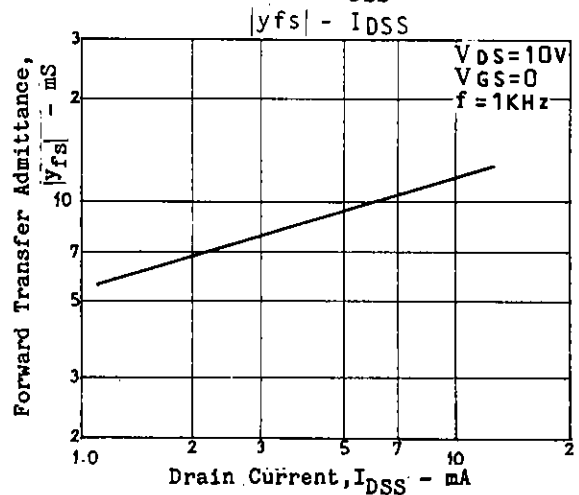
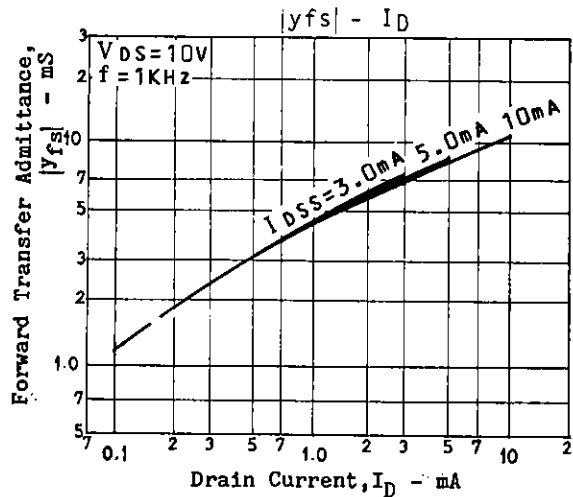
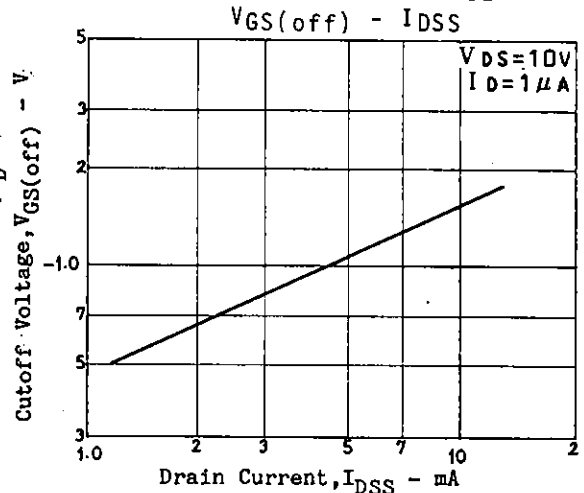
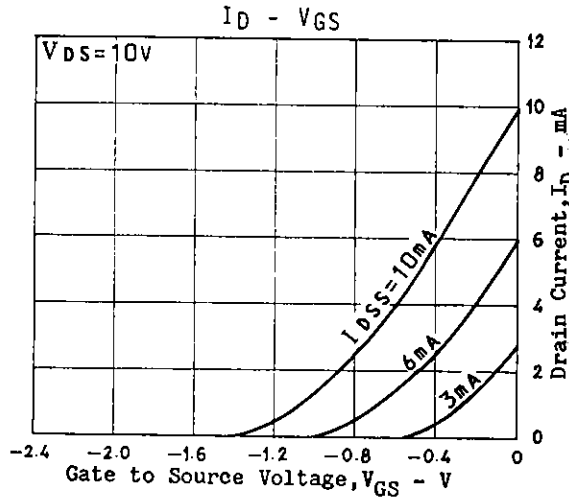
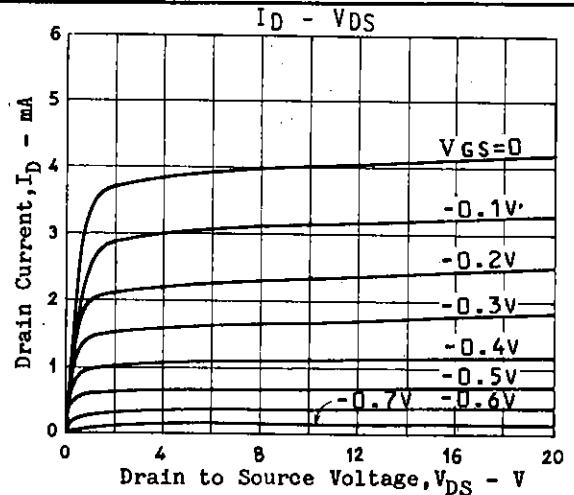
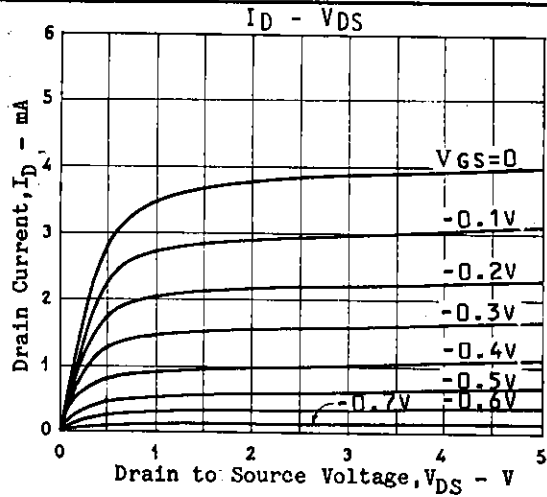


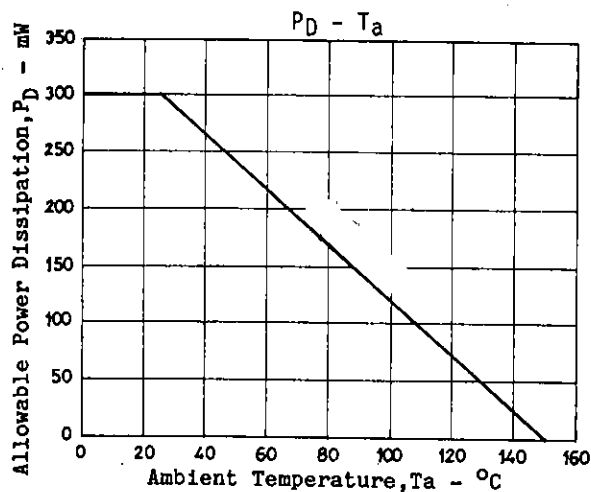
D: Drain
G: Gate
S: Source

SANYO: SPA

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